

### PH800DBR 800nm Series

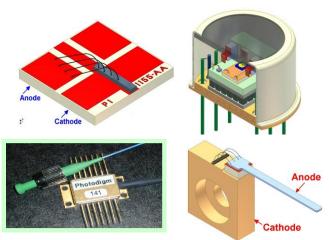
## **High-Power Single-Frequency Laser Diode**

### Technology

- DBR Single-Frequency Laser Chip
- InGaAs QW Active Layer
- Epi designed for high reliability

#### Features

- Available in several package styles
- Pulsed operation for spectral stability at short pulse lengths
- High power for CW applications
- High Slope Efficiency



### Description

The PH800DBR Series of high-power edge-emitting lasers are based on Photodigm's advanced singlefrequency laser technology. It provides a diffraction limited, single lateral and longitudinal mode beam. Facets are passivated for high-power reliability. Devices used in atomic spectroscopy based applications.

### **Absolute Maximum Ratings**

Parameter	Symbol	Unit	Min	Max
Storage Temperature	T <sub>STG</sub>	С°	0	80
Operating Temperature	T <sub>OP</sub>	С°	5.0	70
CW Laser Forward Current, T=T <sub>op</sub>	I <sub>F</sub>	mA	-	**
Pulsed Laser Forward Current, T=25°C, PW=300 ns, DC=10%	I <sub>F</sub>	А	-	0.5
Laser Reverse Voltage	V <sub>R</sub>	V	-	0.0
Photodiode Forward Current 1/2/	I <sub>P</sub>	mA	-	5.0
Photodiode Reverse Voltage 1/2/	V <sub>R</sub>	V	-	20.0
Photodiode Dark Current, V <sub>R</sub> =10V, LD I <sub>F</sub> =0, 1/2/	I <sub>D</sub>	nA	-	50
TEC Current 1/2/	I <sub>TEC</sub>	А	-1.8	1.8
TEC Voltage 1/2/	V <sub>TEC</sub>	V	-1.9	1.9
Thermistor Current 1/2/	I <sub>THRM</sub>	mA	-	1.0
Thermistor Voltage 1/2/	V <sub>THRM</sub>	V	-	10
ESD (HBM)	-	V	-	500
External Back Reflection	-	dB	-	-14
Lead Soldering Temperature, 10 sec. Max., 1/2/	-	°C	-	260
Fiber Pull Force <u>1</u> /	-	Ν	-	5.0
Fiber Bend Radius <u>1</u> /	-	mm	-	35

1/Butterfly package 2/TO-8 package\*\* Do not exceed drive current or operating power of supplied LIV

# Photodigm VVVAA

# **PRODUCT BULLETIN**

### CW Characteristics at T<sub>C</sub> = 25°C unless otherwise specified

CW Characteristics at T <sub>c</sub> = 25 C unless otherwise specified								
Parameter	Symbol	Unit	Min	Тур	Max			
Center Wavelength	λ <sub>c</sub>	nm	798	800	802			
Optical Output Power @ LIV current	Po	mW	See Power Options Call-out					
Slope Efficiency, <u>1</u> /	$\eta_{d}$	W/A	0.3	0.36				
Slope Efficiency	$\eta_{d}$	W/A	0.6	0.72	-			
Threshold Current	l <sub>th</sub>	mA	-	40	50			
Laser Series Resistance	Rs	Ω	-	2.5	3.5			
Laser Forward Voltage	V <sub>F</sub>	V	-	2.0	2.5			
Thermistor Resistance @ 25°C, <u>1/2</u> /	R <sub>T</sub>	KΩ	-	10	-			
Photodiode Dark Current, V <sub>R</sub> =10V, LD I <sub>F</sub> =0, <u>1/2</u> /	I <sub>D</sub>	nA	-	-	50			
Laser Line Width	Δv	MHz	-	0.5	1			
Beam Divergence @ FWHM	θιι Χ θ⊥	0	-	6 X 32	8 X 34			
Side Mode Suppression Ratio	SMSR	dB	-30	-	-			
Polarization Extinction Ratio, <u>1</u> /	PER	dB	-16	-19	-			
Laser Polarization				TE				
Mode Structure			Fundamental Mode					
	•		•					

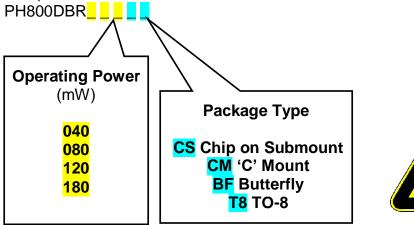
1/Butterfly package 2/TO-8 package

### **Handling Precautions**

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.

### How To Order

Part number example: PH800DBR080CM. Assign optical power from those shown below. Use a three-digit format for all power entries. Call factory for special performance selection and certification to certain atomic absorption lines.





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